NSN 5961-01-076-5818

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-076-5818 **Inclosure Material:** Plastic **Overall Length:** Between 0.765 inches and 0.835 inches **Overall Height:** Between 0.170 inches and 0.190 inches **Overall Width:** Between 0.360 inches and 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 250.0 collector to emitter voltage/static/base open and 300.0 collector to emitter voltage, dc with base short-circuited to emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 0.10 amperes source cutoff current and 0.10 amperes source cutoff current **Power Rating Per Characteristic:** 9.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No